

Features

- Low forward voltage drop
- Soft recovery
- Hermetic metal cases with ceramic insulators

I_{F(AV)} **210A**
V_{RRM} **4000~5000V**
t_{rr} **4 μs**

**Typical Applications**

- Inverters and choppers
- AC. motor control
- Snubber and free-wheeling diodes

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Double side cooled,	125			210	A
V _{RRM}	Repetitive peak reverse voltage	tp=10ms	125	4000		5000	V
I _{RRM}	Repetitive peak current	at V _{RRM}	125			20	mA
I _{fsm}	Surge forward current	10ms half sine wave V _R =0.6V _{RRM}	125			2.7	kA
I ² t	I ² T for fusing coordination					36.5	A ² s*10 ³
V _{FO}	Threshold voltage		125			1.36	V
r _F	Forward slop resistance					3.63	mΩ
V _{FM}	Peak forward voltage	I _{FM} =500A, F=5.0kN	125			3.18	V
I _m	Reverse recovery current	I _{FM} =500A, tp=2000μs, di/dt=-60A/μs, V _R =50V	125		40		A
t _{rr}	Reverse recovery time				4		μs
Q _{rr}	Recovery charge				80		μC
R _{th(j-c)}	Thermal resistance Junction to case	DC double side cooled Clamping force 5.0kN				0.080	°C/W
R _{th(c-h)}	Thermal resistance case to heat sink					0.020	
F _m	Mounting force			3.3		5.5	kN
T _{stg}	Stored temperature			-40		160	°C
W _t	Weight				60		g
Outline		P32					

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FAST RECOVERY DIODE

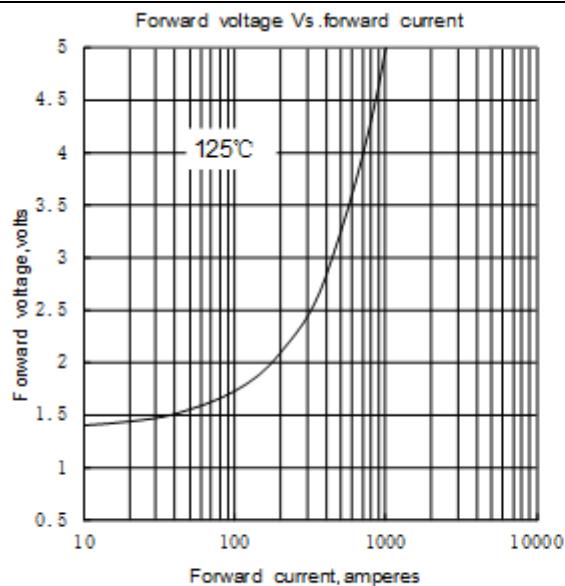
FH210DF**

Fig.1

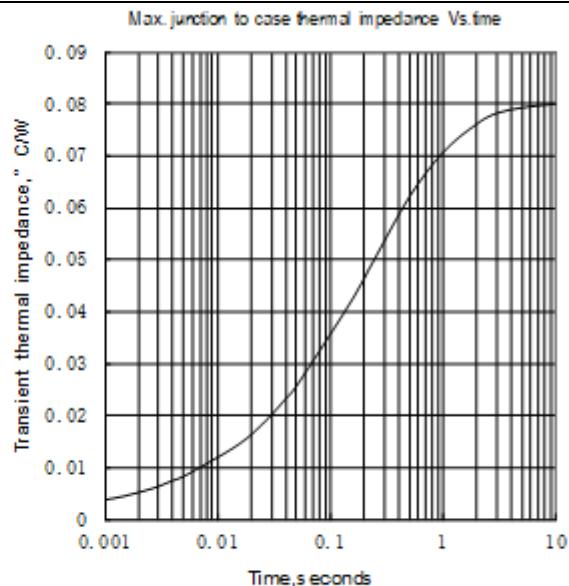


Fig.2

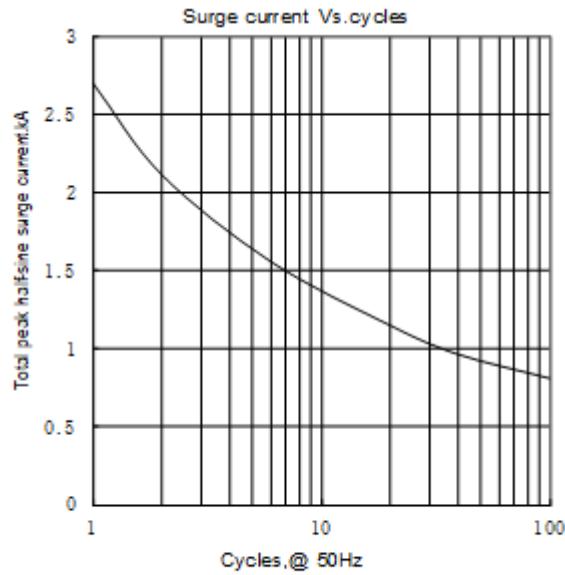
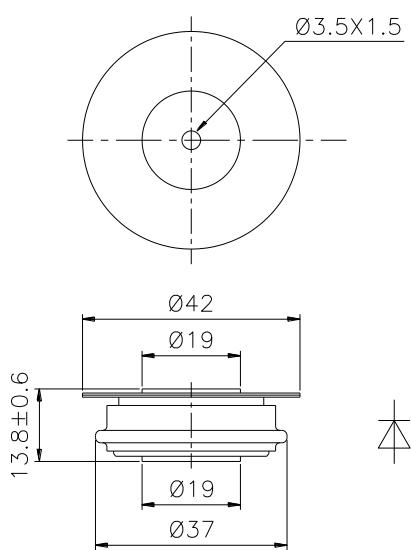


Fig.3



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